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Numerical Simulation of Piezoelectrically Agitated Surface Acoustic Waves on Microfluidic Biochips

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Abstract. Microfluidic biochips are biochemical laboratories on the microscale that are used for genotyping and sequencing in genomics, protein profiling in proteomics, and cytometry cell analysis. There are basically two classes of such biochips: active devices, where the solute transport on a network of channels on the chip surface is realized by external forces, and passive chips, where this is done using a specific design of the geometry of the channel network. Among the active biochips, current interest focuses on devices whose operational principle is based on piezoelectrically driven surface acoustic waves generated by interdigital transducers placed on the chip surface.

In this paper, we are concerned with the numerical simulation of such piezoelectrically agitated surface acoustic waves relying on a mathematical model that describes the coupling of the underlying piezoelectric and elastomechanical phenomena. Since the interdigital transducers usually operate at a fixed frequency, we focus on the time-harmonic case. Its variational formulation gives rise to a generalized saddle point problem for which a Fredholm alternative is shown to hold true.

The discretization of time-harmonic surface acoustic wave equations is taken care of by continuous, piecewise polynomial finite elements with respect to a nested hierarchy of simplicial triangulations of the computational domain. The resulting algebraic saddle point problems are solved by block-diagonally preconditioned iterative solvers with preconditioners of BPX-type. Numerical results are given both for a test problem documenting the performance of the iterative solution process and for a realistic surface acoustic wave device illustrating the properties of surface acoustic wave propagation on piezoelectric materials.

1 Introduction

Biochips, of the microarray type, are fast becoming the default tool for combinatorial chemical and biological analysis in environmental and medical studies. Programmable biochips are miniaturized biochemical labs that are physically and/or electronically controllable. This technology combines digital photolithography, microfluidics and chemistry. The precise positioning of the samples (e.g., DNA solutes or proteins) on the surface of the chip in pico- to nano-liter volumes can be done either by means of external forces (active devices) or by specific geometric patterns (passive devices).

During the last couple of years, such biochips have attracted a considerable amount of interest, since pharmacology, molecular biology, and clinical diagnostics require the precise handling of precious, tiny samples and costly reagents in amounts of nano-liters. Biochips can transport such volumes and perform biochemical analysis of the samples. Microfluidic biochips and microarrays are used in pharmaceutical, medical and forensic applications as well as in academic research and development for high throughput screening, genotyping and sequencing by hybridization in genomics, protein profiling in proteomics, and cytometry in cell analysis [42]. Traditional technologies rely on fluorescent dyes, radioactive markers, or nano-scale gold-beads based on positive hybridization processes. However, these methods only allow a relatively small number of DNA probes per assay, and they only yield endpoint results and do not provide information about the kinetics of the processes. With the need for better sensitivity, flexibility, cost-effectiveness and a significant speed-up of hybridization, the current technological trend is obtained by the integration of the microfluidics on the chips itself. Very recent and novel devices are surface acoustic wave driven microfluidic biochips whose operational mode is based on piezoelectrically actuated surface acoustic waves on the surface of a chip which transport the droplet containing probe along a lithographically produced network to marker molecules placed at pre-specified surface lo-

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complement system by preconditioned iterative solvers with block-diagonal multilevel preconditioners of BPX-type. Finally, in Section 7 we provide a detailed documentation of numerical results illustrating the performance of the iterative solvers as well as the properties of surface acoustic wave propagation on a realistic piezoelectrical SAW device.

2 The theory of piezoelectricity

In piezoelectric materials, the mechanical stress $\boldsymbol{\sigma}$ depends linearly on the electric field \mathbf{E} , in contrast to non-piezoelectric materials where the effect is quadratic.

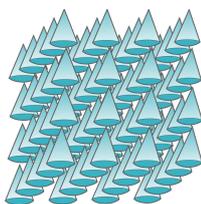


Fig. 4. Polar axis of a piezoelectric crystal

Piezoelectric materials also show the reverse effect to generate an electric field when subjected to mechanical stress. These properties are called the piezoelectric effect and the inverse piezoelectric effect, respectively. The origin of the piezoelectric effect is related to an asymmetry in the unit cell of a piezoelectric crystal and can be observed only in materials with a polar axis, i.e., in face of a rotational symmetry around this axis there are differences in the two directions of this axis (cf. Figure 4). Crystallographers recognize thirty-two classes of crystals of which twenty exhibit the piezoelectric effect. Figure 5 (right) shows a traditional "PZT" piezoelectric material consisting of a small, tetravalent metal ion, usually titanium or zirconium, in a lattice of larger divalent metal ions, usually lead or barium, and O_2 -ions. Such materials show a simple cubic symmetry above the Curie temperature and are thus isotropic before poling. After poling, they exhibit a tetragonal symmetry below the Curie temperature (see Figure 5 (right)). Above this temperature, they lose the piezoelectric properties again.

Although the magnitudes of piezoelectric voltages, movements, or forces are small, and often require amplification (for instance, a typical disc of piezoelectric ceramic will increase or decrease in thickness by only a small fraction of a millimeter), piezoelectric materials have been adapted to a wide range of applications: The piezoelectric effect is used in sensing applications, such as in force or displacement sensors. The inverse piezoelectric effect is used in actuation applications, for instance in motors and devices that precisely control positioning, and in generating sonic and ultrasonic signals. Typical piezoelectric materials are quartz (SiO_2), lithium niobate ($LiNbO_3$) or barium titanate ($BaTiO_3$).

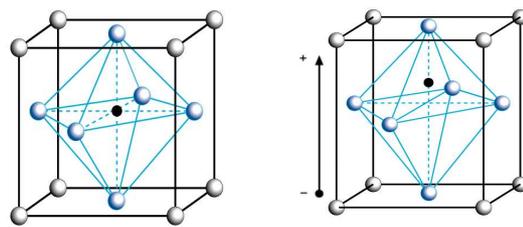


Fig. 5. Crystallographic structure of a "PZT" material: Temperature above (left) and below (right) the Curie point

In the sequel, we consider a linear model for piezoelectricity in which the elastic, piezoelectric and dielectric coefficients are treated as constants independent of the magnitude and frequency of the applied mechanical stresses and electric fields. The model is macroscopic, i.e., only mean values of the relevant physical magnitudes are incorporated. Real materials involve microscopic effects as well as mechanical and electric dissipation and nonlinear behavior. For further reference on piezoelectric problems we refer to [18, 35] and the references therein.

Denoting by $\Omega \subset \mathbb{R}^d$, $d = 2$ or $d = 3$ a Lipschitz domain and by $[0, T] \subset \mathbb{R}_+$ a time interval, the mechanical displacement $\mathbf{u} = \mathbf{u}(\mathbf{x}, t)$ of a piezoelectric material, occupying Ω and being exposed to a volume force \mathbf{b} , is described by the wave equation

$$\rho \frac{\partial^2 \mathbf{u}}{\partial t^2} - \nabla \cdot \boldsymbol{\sigma} = \mathbf{b} \quad \text{in } Q := \Omega \times [0, T]. \quad (1)$$

Here, ρ is the density and $\boldsymbol{\sigma} = (\sigma_{ij})$ stands for stress tensor. The stress tensor is related to the linearized strain tensor $\boldsymbol{\varepsilon} = \frac{1}{2}(\nabla \mathbf{u} + (\nabla \mathbf{u})^T)$ by the constitutive equation (generalized Hooke's law)

$$\sigma_{ij}(\mathbf{u}, \mathbf{E}) = c_{ijkl} \varepsilon_{kl}(\mathbf{u}) - e_{kij} E_k. \quad (2)$$

Here, $\mathbf{E} = (E_k)$ denotes the electric field, $\mathbf{c} = (c_{ijkl})$ is the symmetric, positive definite fourth-order elasticity tensor and $\mathbf{e} = (e_{kij})$ refers to the symmetric third-order piezoelectric tensor. Note that here and in the sequel we adopt Einstein's summation convention.

In piezoelectric materials, the frequency of the occurring electric field wave is considered sufficiently small so that the coupling of electromagnetic waves and elastic waves can be neglected. This means that local perturbations in the electromagnetic field are felt almost instantaneously throughout the domain, so that the electric field can be treated as quasi-static. Practically, this can be achieved by setting the magnetic permeability to zero, corresponding to an infinite speed of the electromagnetic wave. Maxwell's second equation then reduces to $\nabla \times \mathbf{E} = \mathbf{0}$, i.e., the electric field is irrotational and thus can be represented as the gradient of an electric scalar potential Φ according to $\mathbf{E} = -\nabla \Phi$. When the electric field \mathbf{E} is known, the magnetic field \mathbf{H} can be obtained from Maxwell's first equation. However, the magnetic field is usually not of interest in piezoelectric computations and is therefore not considered further. Moreover,

piezoelectric substrates are nearly perfect isolators, i.e., the density of the free electric charges and the current density can be completely neglected. Consequently, the only relevant Maxwell equation is $\nabla \cdot \mathbf{D} = 0$, where $\mathbf{D} = \mathbf{D}(\mathbf{x}, t)$ is the electric displacement that is related to the electric field \mathbf{E} by the constitutive equation

$$D_i = \epsilon_{ij} E_j + P_i .$$

Here, $\mathbf{P} = (P_i)$ is the electric polarization and $\epsilon = (\epsilon_{ij})$ stands for the symmetric, positive definite permittivity tensor.

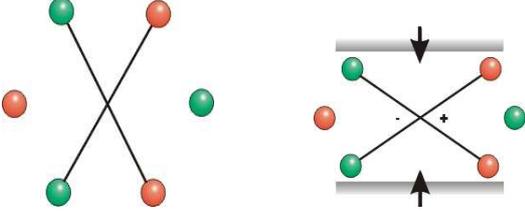


Fig. 6. The formation of an electric dipole by pressure

Figure 6 shows a schematic explanation for the formation of a polarization \mathbf{P} in an atomic structure when subjected to external stress: In both cases one can see six "point charges", "red" indicating positive and "green" negative charges. In a relaxed state with no forces acting on them, they are arranged at the vertices of an hexagon. In some distance, the positive and negative array of charges will cancel each other out and the potential Φ will be zero. If a compressive force is applied to the hexagon, the array is distorted in such a way as to bring two of the positive charges closer together at one end and the negative charges at the other. This forms a dipole where one end of the array is positive and the other one is negative. One can easily imagine a crystal structure made up of these hexagonal arrangements of ions.

In piezoelectric materials, the polarization according to external strain is linear. In analogy to the inverse effect (2), we set

$$D_i(\mathbf{u}, \mathbf{E}) = e_{ikl} \epsilon_{kl}(\mathbf{u}) + \epsilon_{ij} E_j . \quad (3)$$

Summarizing, the linear field equations of piezoelectricity are given by

$$\rho \frac{\partial^2 u_i}{\partial t^2} - c_{ijkl} u_{k,lj} - e_{kij} \Phi_{,kj} = b_i \quad \text{in } Q , \quad (4)$$

$$e_{ikl} u_{k,li} - \epsilon_{ij} \Phi_{,ji} = 0 \quad \text{in } Q . \quad (5)$$

and the constitutive equations

$$\sigma_{ij}(\mathbf{u}, \Phi) = c_{ijkl} \epsilon_{kl}(\mathbf{u}) + e_{kij} \Phi_{,k} , \quad (6)$$

$$D_i(\mathbf{u}, \Phi) = e_{ikl} \epsilon_{kl}(\mathbf{u}) - \epsilon_{ij} \Phi_{,j} . \quad (7)$$

The boundary $\partial\Omega$ is partitioned into two disjoint sets according to

$$\begin{aligned} \partial\Omega &= \Gamma_u \cup \Gamma_\sigma , & \Gamma_\sigma &= \partial\Omega \setminus \Gamma_u , \\ \partial\Omega &= \Gamma_\Phi \cup \Gamma_D , & \Gamma_D &= \partial\Omega \setminus \Gamma_\Phi , \end{aligned}$$

where the Dirichlet boundaries Γ_u and Γ_Φ are assumed to be closed and with non-vanishing $(d-1)$ -dimensional measure. The piezoelectric equations are supplemented by the decoupled boundary conditions

$$\mathbf{u}|_{\Gamma_u} = \mathbf{u}_\Gamma , \quad \text{where } \partial\Omega = \Gamma_u \cup \Gamma_\sigma , \quad (8)$$

$$\boldsymbol{\sigma} \cdot \mathbf{n}|_{\Gamma_\sigma} = \boldsymbol{\sigma}_n ,$$

$$\Phi|_{\Gamma_\Phi} = \Phi_\Gamma , \quad \text{where } \partial\Omega = \Gamma_\Phi \cup \Gamma_D , \quad (9)$$

$$\mathbf{D} \cdot \mathbf{n}|_{\Gamma_D} = D_n ,$$

and by the initial conditions

$$\mathbf{u}(\mathbf{x}, 0) = \mathbf{u}_0(\mathbf{x}) , \quad \frac{\partial \mathbf{u}}{\partial t}(\mathbf{x}, 0) = \mathbf{u}_1(\mathbf{x}) . \quad (10)$$

Sometimes, it is useful to adopt a compressed notation for the piezoelectric moduli, the Voigt notation (see, e.g., [18, 35, 61]). By utilizing the symmetry properties of the third- and fourth-order tensors they can be reduced to higher dimensional second-order matrices. To this end, we use the identification $I = (ij)$, where

(ij)	(11)	(22)	(33)	(23)	(13)	(12)
I	1	2	3	4	5	6

i.e., $c_{IK} = c_{ijkl}$, $e_{iK} = e_{ikl}$ and $\epsilon_I = \epsilon_{ij}$. With this notation, the characteristic properties of a linear piezoelectric substrate are completely determined by the material matrix

$$\begin{pmatrix} c_{IK} & e_{Ki}^T \\ e_{iK} & \epsilon_{ij} \end{pmatrix} = \begin{pmatrix} \begin{bmatrix} c_{11} & c_{12} & c_{13} & c_{14} & c_{15} & c_{16} \\ c_{12} & c_{22} & c_{23} & c_{24} & c_{25} & c_{26} \\ c_{13} & c_{23} & c_{33} & c_{34} & c_{35} & c_{36} \\ c_{14} & c_{24} & c_{34} & c_{44} & c_{45} & c_{46} \\ c_{15} & c_{25} & c_{35} & c_{45} & c_{55} & c_{56} \\ c_{16} & c_{26} & c_{36} & c_{46} & c_{56} & c_{66} \end{bmatrix} & \begin{bmatrix} e_{11} & e_{21} & e_{31} \\ e_{12} & e_{22} & e_{32} \\ e_{13} & e_{23} & e_{33} \\ e_{14} & e_{24} & e_{34} \\ e_{15} & e_{25} & e_{35} \\ e_{16} & e_{26} & e_{36} \end{bmatrix} \\ \begin{bmatrix} e_{11} & e_{12} & e_{13} & e_{14} & e_{15} & e_{16} \\ e_{21} & e_{22} & e_{23} & e_{24} & e_{25} & e_{26} \\ e_{31} & e_{32} & e_{33} & e_{34} & e_{35} & e_{36} \end{bmatrix} & \begin{bmatrix} \epsilon_{11} & \epsilon_{12} & \epsilon_{13} \\ \epsilon_{12} & \epsilon_{22} & \epsilon_{23} \\ \epsilon_{13} & \epsilon_{23} & \epsilon_{33} \end{bmatrix} \end{pmatrix} .$$

The matrices c_{IK} and ϵ_{ij} are symmetric with respect to the main diagonal and hence, there are $21 + 18 + 6 = 45$ independent moduli for the most general piezoelectric substrates.

3 Piezoelectrically driven surface acoustic waves

3.1 Surface Acoustic Wave Devices

Surface acoustic waves (SAWs) are modes of elastic energy propagating at the surface of a solid body. Being the nano-meter size analogon of earthquakes, they have been made available to industrial applications during the last two decades. The underlying technique is relatively new, although the first theoretical treatments on the propagation of surface acoustic waves at the free surface of a homogenous isotropic elastic solid date back approximately 150 years (cf. [44]). But it was not before White and Voltmer [53] succeeded in the production of SAWs on the surface of a piezoelectric substrate that the use of this technology became clear. Nowadays, piezoelectric

SAW devices are very popular in signal-processing applications (see, e.g., [13,20,30,36]), which is mostly due to the fact that on homogenous substrates the velocity of SAWs is independent of their frequency.

SAWs are easily excited on piezoelectric solids, because substrates deform due to the application of an electric field. Rapid changes of these electric fields are efficiently converted into a real 'nano-quake on a chip'. Such rapid changes can be generated by a metallic electrode comb structure, called interdigital transducer (IDT), deposited on the surface of the piezoelectric material (see Figure 7). By applying an alternating voltage to the IDT,

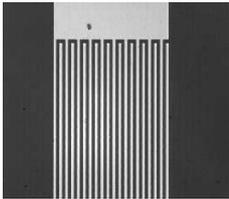


Fig. 7. Interdigital transducer

a surface acoustic wave is excited [39]. Typical frequencies range in the hundred MHz regime, typical wavelengths of SAW are micrometers. Since the SAW components can be manufactured using advanced photolithographic techniques, they meet the requirements of small size and weight. This is also the reason why SAW devices can be mass produced using the same techniques as in semiconductor microfabrication. They receive outstanding response characteristics, especially in filter applications.

Unfortunately, the excitation of an IDT on a piezoelectric substrate can also lead to the generation of bulk acoustic waves (BAWs) as well as surface waves. In most applications, such BAWs are certainly undesirable, e.g., in signal processing applications they seriously degrade the filter response. In most analytical treatments, BAWs are neglected.

The typical dimensions of an SAW chip are only a few millimeters, depending on the operating frequency. A wide range of piezoelectric materials are used for the production of SAW devices, among them lithium niobate (LiNbO_3), lithium tantalate (LiTaO_3), and quartz (SiO_2) monocrytals.

3.2 Physical Modeling of Rayleigh Waves

The type of surface waves considered here are so-called Rayleigh waves (see, e.g., [3,34]), i.e., these are waves polarized in the sagittal plane and propagating at the free surface at a speed less than that of volume shear elastic waves. These waves usually are considered in a semi-infinite, isotropic and homogenous linear elastic space, which will be fixed as in Figure 8 (left).

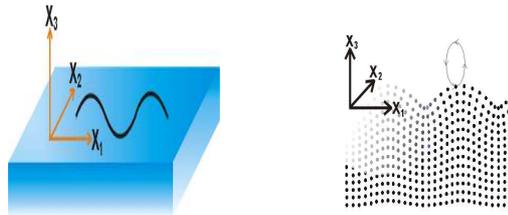


Fig. 8. Modeling of surface acoustic waves. Coordinate system (left) and Rayleigh wave (right)

The sagittal plane is the plane spanned by the real wave-vector \mathbf{k} and the unit surface normal, i.e., the (x_1, x_3) -plane in Figure 8 (left). SAWs are strictly confined to the limiting surface of the piezoelectric substrate and practically nil outside a relatively narrow zone. To be precise, the amplitude of the displacement \mathbf{u} decays exponentially with depth into the substrate [35]. In true Rayleigh waves, most of the energy (90%) is concentrated within one wavelength from the surface. Thus, both the mechanical displacements \mathbf{u} and the electric potential Φ should vanish as $x_3 \rightarrow \infty$. Moreover, since x_1 is the direction of propagation of the wave solutions, there is no dependence of \mathbf{u} and Φ on the x_2 coordinate, since here the surface is assumed to be infinite.

We note that in the physical modeling of surface acoustic waves the assumption of an x_2 -independence is extremely simplifying, since piezoelectric materials are in general anisotropic and pure Rayleigh surface acoustic waves can be observed only in rare crystal cuts.

The two wave motions in the x_1 - and x_3 -direction are 90° out of phase in the time domain: if one wave component is at its maximum for a given instant, the other will be zero. Moreover, the displacement in the x_3 -direction will be larger than that in the x_1 -direction. These considerations give rise to

$$\begin{aligned} u_i(x_1, x_3, t) &= \alpha_i \exp(-\beta k x_3) \exp(i(\omega t - k x_1)) , \\ \Phi(x_1, x_3, t) &= \alpha_4 \exp(-\beta k x_3) \exp(i(\omega t - k x_1)) , \end{aligned}$$

with $\text{Re}(\beta) > 0$. Hereafter, i denotes the imaginary unit and k the modulus of the wave-vector \mathbf{k} . In some sense the factor β measures the rate of exponential decay into the substrate. We insert these functions into the piezoelectric equations by

$$\begin{aligned} \rho \frac{\partial^2 u_i}{\partial t^2} - c_{ijkl} \frac{\partial^2 u_k}{\partial x_l \partial x_j} - e_{kij} \frac{\partial^2 \Phi}{\partial x_k \partial x_j} &= 0 , \\ e_{ikl} \frac{\partial^2 u_k}{\partial x_l \partial x_i} - \epsilon_{ij} \frac{\partial^2 \Phi}{\partial x_j \partial x_i} &= 0 . \end{aligned}$$

This leads to a linear system for the coefficients α_i of the form

$$\mathbf{M} \boldsymbol{\alpha} = 0 .$$

Here, $\boldsymbol{\alpha} = (\alpha_i) \in \mathbb{C}^4$, $\mathbf{M} = (M_{kl}) \in \mathbb{C}^{4 \times 4}$, and the coefficients M_{kl} are quadratic functions in β . For the existence of nontrivial solutions, we have to require that

$\det \mathbf{M} = 0$. Accounting for $\text{Re}(\beta) > 0$, we get 4 possible values for β . For each such β , there is an eigenvector $\boldsymbol{\alpha}$.

The general solution is then obtained as a linear combination of these solutions

$$\begin{aligned} u_i(x_1, x_3, t) &= \exp(i(\omega t - kx_1)) \cdot \\ &\quad \sum_{m=1}^4 c^{(m)} \alpha_i^{(m)} u_i^{0(m)} \exp(-\beta^{(m)} kx_3), \\ \Phi(x_1, x_3, t) &= \exp(i(\omega t - kx_1)) \cdot \\ &\quad \sum_{m=1}^4 c^{(m)} \alpha_4^{(m)} \Phi^{0(m)} \exp(-\beta^{(m)} kx_3). \end{aligned}$$

We note that the weighting factors $c^{(m)}$, representing the value of the phase velocity, have to be chosen according to the boundary conditions.

The use of anisotropic materials causes many differences in detail even though the occurring surface waves share many features. For instance, the waves are still elliptically polarized at each depth and the displacement amplitude decays exponentially into the substrate. But in anisotropic materials, the phase velocity depends on the direction of propagation and in general, the vector of energy flow is not parallel to the wave vector. Moreover, the plane of the elliptical polarization of the displacement does not necessarily correspond to the sagittal plane, but even when it does, the principal axes of the ellipse are not necessarily x_1 and x_3 .

4 Mathematical theory of piezoelectric SAWs

Surface acoustic waves are usually excited by a source interdigital transducer located at Γ_Φ and operating at a fixed frequency $\omega > 0$. We treat the excitation as a Dirichlet boundary condition for the electric potential Φ and assume that there is no further volume force \mathbf{b} . Consequently, the piezoelectric equations reduce to

$$\rho \frac{\partial^2 u_i}{\partial t^2} - c_{ijkl} \frac{\partial^2 u_k}{\partial x_l \partial x_j} - e_{kij} \frac{\partial^2 \Phi}{\partial x_k \partial x_j} = 0, \quad (11)$$

$$e_{ikl} \frac{\partial^2 u_k}{\partial x_l \partial x_i} - \epsilon_{ij} \frac{\partial^2 \Phi}{\partial x_j \partial x_i} = 0. \quad (12)$$

Hereafter, we use without loss of generality $\rho = 1$. We are now looking for time harmonic solutions

$$\mathbf{u}(\mathbf{x}, t) = \text{Re}(\mathbf{u}(\mathbf{x}) \exp(-i\omega t)), \quad (13)$$

$$\Phi(\mathbf{x}, t) = \text{Re}(\Phi(\mathbf{x}) \exp(-i\omega t)), \quad (14)$$

where the functions \mathbf{u} and Φ are complex valued. The boundary conditions are assumed to be of the same form

$$\mathbf{u}(\mathbf{x}, t) = \text{Re}(\mathbf{u}_\Gamma(\mathbf{x}) \exp(-i\omega t)), \quad (15a)$$

$$\boldsymbol{\sigma}(\mathbf{x}, t) \cdot \mathbf{n} = \text{Re}(\boldsymbol{\sigma}_n(\mathbf{x}) \exp(-i\omega t)), \quad (15b)$$

$$\Phi(\mathbf{x}, t) = \text{Re}(\Phi_\Gamma(\mathbf{x}) \exp(-i\omega t)), \quad (15c)$$

$$\mathbf{D}(\mathbf{x}, t) \cdot \mathbf{n}|_{\Gamma_D} = \text{Re}(D_n(\mathbf{x}) \exp(-i\omega t)). \quad (15d)$$

For the variational formulation of (11),(12), (15a)-(15d) we adopt standard notation of Lebesgue and Sobolev space theory (cf., e.g., [1,21,37]). We denote by $L^2(\Omega)$ and $\mathbf{L}^2(\Omega)$ the Lebesgue of square integrable complex valued functions respectively vector fields on Ω with inner product $(\cdot, \cdot)_{0,\Omega}$ and norm $\|\cdot\|_{0,\Omega}$. We use $H^k(\Omega)$, $\mathbf{H}^k(\Omega)$ for the Sobolev space of complex valued square integrable functions/vector fields having square integrable weak derivatives up to order $k \in \mathbb{N}$ with inner product $(\cdot, \cdot)_{k,\Omega}$ and norm $\|\cdot\|_{k,\Omega}$. For $\Gamma' \subseteq \partial\Omega$, we refer to $H^{\frac{1}{2}}(\Gamma')$ and $\mathbf{H}^{\frac{1}{2}}(\Gamma')$ as the trace space associated with $H^1(\Omega)$ and $\mathbf{H}^1(\Omega)$. The subspaces $H_{0,\Gamma'}^1(\Omega)$, $\mathbf{H}_{0,\Gamma'}^1(\Omega)$ stand for the subspaces of functions/vector fields on Ω with vanishing trace on Γ' (omitting the subindex Γ' , if $\Gamma' = \partial\Omega$). We denote by $H_{00}^{\frac{1}{2}}(\Gamma') \subset H^{\frac{1}{2}}(\Gamma')$ and $\mathbf{H}_{00}^{\frac{1}{2}}(\Gamma') \subset \mathbf{H}^{\frac{1}{2}}(\Gamma')$ the subspaces of functions/vector fields whose extension by zero to all of $\partial\Omega$ belongs to $H^{\frac{1}{2}}(\partial\Omega)$ ($\mathbf{H}^{\frac{1}{2}}(\partial\Omega)$) and defines a bounded linear operator. The associated dual spaces are referred to as $H^{-\frac{1}{2}}(\Gamma')$ and $\mathbf{H}^{-\frac{1}{2}}(\Gamma')$.

For the ease of notation, we set $\mathbf{V} := \mathbf{H}_{0,\Gamma_u}^1(\Omega)$, $W := H_{0,\Gamma_\Phi}^1(\Omega)$, and we denote by \mathbf{V}^* and W^* the associated dual spaces. As far as the elastic and electric Dirichlet boundary data are concerned, we assume $\mathbf{u}_\Gamma \in \mathbf{H}^{\frac{1}{2}}(\Gamma_u)$ as well as $\Phi_\Gamma \in H^{\frac{1}{2}}(\Gamma_\Phi)$. We denote by $\mathbf{E}_{\Gamma_u} : \mathbf{H}^{\frac{1}{2}}(\Gamma_u) \rightarrow \mathbf{H}^1(\Omega)$ and by $E_{\Gamma_\Phi} : H^{\frac{1}{2}}(\Gamma_\Phi) \rightarrow H^1(\Omega)$ the harmonic extension operators with $\mathbf{E}_{\Gamma_u}(\mathbf{u}_\Gamma)|_{\Gamma_u} = \mathbf{u}_\Gamma$ and $E_{\Gamma_\Phi}(\Phi_\Gamma)|_{\Gamma_\Phi} = \Phi_\Gamma$, and we introduce the subspaces

$$\mathbf{V}_{\Gamma_u} := \mathbf{V} + \mathbf{E}_{\Gamma_u}(\mathbf{u}_\Gamma), \quad (16a)$$

$$W_{\Gamma_\Phi} := W + E_{\Gamma_\Phi}(\Phi_\Gamma). \quad (16b)$$

For the elastic and electric Neumann boundary data we suppose that $\boldsymbol{\sigma}_n \in \mathbf{H}^{-\frac{1}{2}}(\Gamma_\sigma)$ and $D_n \in H^{-\frac{1}{2}}(\Gamma_D)$. We refer to $\mathbf{R}_{\Gamma_\sigma} : \mathbf{H}^1(\Omega) \rightarrow \mathbf{H}^{-\frac{1}{2}}(\Gamma_\sigma)$ and $R_{\Gamma_D} : \mathbf{H}^1(\Omega) \rightarrow H^{-\frac{1}{2}}(\Gamma_D)$ as the trace operators with $\mathbf{R}_{\Gamma_\sigma}(\mathbf{u}) = (\boldsymbol{\sigma}(\mathbf{u}) \cdot \mathbf{n})|_{\Gamma_\sigma}$ and $R_{\Gamma_D}(\Phi) = (\nabla\Phi \cdot \mathbf{n})|_{\Gamma_D}$. We further introduce the sesquilinear forms

$$a(\mathbf{v}, \mathbf{w}) := \int_{\Omega} c_{ijkl} \varepsilon_{kl}(\mathbf{v}) \varepsilon_{ij}(\overline{\mathbf{w}}) \, d\mathbf{x},$$

$$b(\varphi, \mathbf{v}) := \int_{\Omega} e_{kij} \frac{\partial \varphi}{\partial x_k} \varepsilon_{ij}(\overline{\mathbf{v}}) \, d\mathbf{x},$$

$$c(\varphi, \psi) := \int_{\Omega} \epsilon_{ij} \frac{\partial \varphi}{\partial x_i} \frac{\partial \overline{\psi}}{\partial x_j} \, d\mathbf{x},$$

where $\mathbf{v}, \mathbf{w} \in \mathbf{H}^1(\Omega)$ and $\varphi, \psi \in H^1(\Omega)$ with $\overline{\mathbf{w}}$ and $\overline{\psi}$ denoting the complex conjugation.

The variational formulation of the problem of piezoelectrically driven surface acoustic waves then reads:

Find $\mathbf{u} \in \mathbf{V}_{\Gamma_u}$ and $\Phi \in W_{\Gamma_\Phi}$ such that for all $\mathbf{v} \in \mathbf{V}$ and $\psi \in W$

$$a(\mathbf{u}, \mathbf{v}) + b(\Phi, \mathbf{v}) - \omega^2(\mathbf{u}, \mathbf{v})_{0,\Omega} = \langle \boldsymbol{\sigma}_n, \mathbf{v} \rangle, \quad (18a)$$

$$b(\psi, \mathbf{u}) - c(\Phi, \psi) = \langle D_n, \psi \rangle. \quad (18b)$$

Hereafter, $\langle \cdot, \cdot \rangle$ stands both for the dual pairing between $H^{-\frac{1}{2}}(\Gamma_\sigma)$ and $H_{00}^{\frac{1}{2}}(\Gamma_\sigma)$ and for the dual pairing between $H^{-\frac{1}{2}}(\Gamma_D)$ and $H_{00}^{\frac{1}{2}}(\Gamma_D)$.

The above sesquilinear forms define linear operators $\mathbf{A} : \mathbf{H}^1(\Omega) \rightarrow \mathbf{V}^*$, $\mathbf{B} : H^1(\Omega) \rightarrow \mathbf{V}^*$ and $\mathbf{C} : H^1(\Omega) \rightarrow W^*$ so that (18a),(18b) can be written in operator form as:

Find $\mathbf{u} \in \mathbf{V}$ and $\Phi \in W$ such that

$$(\mathbf{A} - \omega^2 \mathbf{I})\mathbf{u} + \mathbf{B}\Phi = \mathbf{f}, \quad (19a)$$

$$\mathbf{B}^*\mathbf{u} - \mathbf{C}\Phi = g, \quad (19b)$$

where \mathbf{I} stands for the injection $\mathbf{I} : \mathbf{V} \rightarrow \mathbf{V}^*$ and the right-hand sides $\mathbf{f} \in \mathbf{V}^*$, $g \in W^*$ are given by

$$\mathbf{f} := \mathbf{R}_{\Gamma_\sigma}^*(\boldsymbol{\sigma}_n) - (\mathbf{A} - \omega^2 \mathbf{I})\mathbf{E}_{\Gamma_u}(\mathbf{u}_\Gamma) - \mathbf{B}\mathbf{E}_{\Gamma_\Phi}(\Phi_\Gamma),$$

$$g := \mathbf{R}_{\Gamma_D}^*(D_n) - \mathbf{B}^*\mathbf{E}_{\Gamma_u}(\mathbf{u}_\Gamma) + \mathbf{C}\mathbf{E}_{\Gamma_\Phi}(\Phi_\Gamma).$$

Lemma 4.1. *The operators \mathbf{A} , \mathbf{B} and \mathbf{C} are bounded linear operators. Moreover, the operator \mathbf{A} is symmetric and \mathbf{V} -elliptic, and the operator \mathbf{C} is symmetric and W -elliptic.*

Proof. The continuity of \mathbf{A} , \mathbf{B} and \mathbf{C} follows readily by applying the Cauchy Schwarz inequality. The symmetry of \mathbf{A} results from the symmetry of the elasticity tensor \mathbf{c} , whereas the \mathbf{V} -ellipticity of \mathbf{A} is a direct consequence of the positive definiteness of \mathbf{c} and Korn's inequality. Likewise, the symmetry of \mathbf{C} follows from the symmetry of the piezoelectric tensor $\boldsymbol{\epsilon}$ and the W -ellipticity can be deduced from the positive definiteness of $\boldsymbol{\epsilon}$. \square

The invertibility of \mathbf{C} allows us to eliminate Φ from (19a),(19b) which results in the Schur complement system

$$\mathbf{S}\mathbf{u} - \omega^2 \mathbf{I}\mathbf{u} = \mathbf{F}. \quad (21)$$

Here, the Schur complement operator $\mathbf{S} : \mathbf{V} \rightarrow \mathbf{V}^*$ and the right-hand side \mathbf{F} are given by

$$\mathbf{S} := \mathbf{A} + \mathbf{B}\mathbf{C}^{-1}\mathbf{B}^*, \quad (22)$$

$$\mathbf{F} := \mathbf{f} + \mathbf{B}\mathbf{C}^{-1}g. \quad (23)$$

Lemma 4.2. *The derived Schur complement operator \mathbf{S} is a bounded, symmetric and \mathbf{V} -elliptic linear operator. Denoting by γ_A and γ_C the ellipticity constants of \mathbf{A} and \mathbf{C} , respectively, for the ellipticity constant γ_S of \mathbf{S} and the norm $\|\mathbf{S}\|$ we have the estimates*

$$\|\mathbf{S}\| \leq \|\mathbf{A}\| + \frac{\|\mathbf{B}\|^2}{\gamma_C}, \quad \gamma_S \geq \gamma_A. \quad (24)$$

Proof. The symmetry of \mathbf{S} follows immediately from the symmetry of \mathbf{A} and \mathbf{C} . Moreover, for $\mathbf{v}, \mathbf{w} \in \mathbf{V}$ we have

$$\begin{aligned} \langle \mathbf{S}\mathbf{v}, \mathbf{w} \rangle &= \langle \mathbf{A}\mathbf{v}, \mathbf{w} \rangle + \langle \mathbf{C}^{-1}\mathbf{B}^*\mathbf{v}, \mathbf{B}^*\mathbf{w} \rangle \\ &\leq \left(\|\mathbf{A}\| + \|\mathbf{C}^{-1}\| \|\mathbf{B}\|^2 \right) \|\mathbf{v}\|_{1,\Omega} \|\mathbf{w}\|_{1,\Omega}. \end{aligned}$$

Hence, taking $\|\mathbf{C}^{-1}\| \leq \gamma_C^{-1}$ into account, this gives the upper bound for $\|\mathbf{S}\|$ in (24). The lower bound for γ_S can be readily deduced from

$$\langle \mathbf{S}\mathbf{v}, \mathbf{v} \rangle = \langle \mathbf{A}\mathbf{v}, \mathbf{v} \rangle + \langle \mathbf{C}^{-1}\mathbf{B}^*\mathbf{v}, \mathbf{B}^*\mathbf{v} \rangle \geq \gamma_A \|\mathbf{v}\|_{1,\Omega}^2. \quad \square$$

The Riesz Schauder theory of compact, self-adjoint linear operators is not directly applicable to (21), since the Schur complement operator \mathbf{S} is not a self-adjoint endomorphism. Nevertheless, the Fredholm alternative holds true for (21), as can be seen by introducing the operator $\mathbf{S}_R^{-1} : \mathbf{L}^2(\Omega) \rightarrow \mathbf{V} \subset \mathbf{L}^2(\Omega)$ according to

$$\mathbf{S}_R^{-1}\mathbf{v} := \mathbf{S}^{-1}\mathbf{v}, \quad \mathbf{v} \in \mathbf{L}^2(\Omega). \quad (25)$$

Then, (21) can be rewritten as

$$\mathbf{S}\mathbf{u} - \omega^2 \mathbf{u} = -\omega^2 \mathbf{S} \left(\mathbf{S}_R^{-1} - \omega^{-2} \right) \mathbf{u} = \mathbf{F}, \quad (26)$$

and we obtain the following result:

Theorem 4.1. (Fredholm Alternative)

a) For $\omega^2 \in \mathbb{R}$, exactly one of the following alternatives holds true:

- (1) $\mathbf{u} = \mathbf{0}$ is the only solution of the eigenvalue problem $\mathbf{S}\mathbf{u} = \omega^2 \mathbf{I}\mathbf{u}$. In this case, for every $\mathbf{F} \in \mathbf{V}^*$ the equation $(\mathbf{S} - \omega^2 \mathbf{I})\mathbf{u} = \mathbf{F}$ admits a unique solution $\mathbf{u} \in \mathbf{V}$ depending continuously on \mathbf{F} .
- (2) There is a finite number M of linear independent eigenfunctions $\mathbf{u}_1, \dots, \mathbf{u}_M$ satisfying $\mathbf{S}\mathbf{u}_m = \omega^2 \mathbf{I}\mathbf{u}_m$. In this case, if $\bar{\mathbf{u}}$ solves $(\mathbf{S} - \omega^2 \mathbf{I})\mathbf{u} = \mathbf{F}$ (i.e., if the equation is solvable), the general solution can be obtained with arbitrary $\alpha_m \in \mathbb{R}$ by

$$\mathbf{u} = \bar{\mathbf{u}} + \sum_{m=1}^M \alpha_m \mathbf{u}_m.$$

b) The spectrum of \mathbf{S} consists of a sequence of countably many real eigenvalues $0 < \omega_1^2 < \omega_2^2 < \dots$ tending to infinity, i.e., $\lim_{j \rightarrow \infty} \omega_j^2 = \infty$.

c) If $\omega^2 \in \mathbb{R}$ is an eigenvalue of \mathbf{S} , the equation $(\mathbf{S} - \omega^2 \mathbf{I})\mathbf{u} = \mathbf{F}$ is solvable if and only if $\mathbf{F} \in (\mathbf{S} - \omega^2 \mathbf{I})(\mathbf{V})$, i.e., iff $\mathbf{F} \in \text{Ker}(\mathbf{S} - \omega^2 \mathbf{I})^0$ where

$$\text{Ker}(\mathbf{S} - \omega^2 \mathbf{I})^0 :=$$

$$\{ \mathbf{v}^* \in \mathbf{V}^* \mid \langle \mathbf{v}^*, \mathbf{v} \rangle = 0, \mathbf{v} \in \text{Ker}(\mathbf{S} - \omega^2 \mathbf{I}) \}.$$

Proof. The operator \mathbf{S}_R^{-1} as given by (25) is symmetric in $\mathbf{L}^2(\Omega)$. Indeed, using the symmetry of \mathbf{S} , for $\mathbf{v}, \mathbf{w} \in \mathbf{L}^2(\Omega)$ we obtain

$$\begin{aligned} \langle \mathbf{S}_R^{-1}\mathbf{v}, \mathbf{w} \rangle_{0,\Omega} &= \langle \mathbf{S}_R^{-1}\mathbf{v}, \mathbf{S}\mathbf{S}_R^{-1}\mathbf{w} \rangle_{0,\Omega} \\ &= \langle \mathbf{S}\mathbf{S}_R^{-1}\mathbf{v}, \mathbf{S}_R^{-1}\mathbf{w} \rangle_{0,\Omega} = \langle \mathbf{v}, \mathbf{S}_R^{-1}\mathbf{w} \rangle_{0,\Omega}. \end{aligned}$$

It is bounded, since for $\mathbf{v} \in \mathbf{L}^2(\Omega)$:

$$\begin{aligned} \gamma_S \|\mathbf{S}_R^{-1}\mathbf{v}\|_{0,\Omega}^2 &\leq \gamma_S \|\mathbf{S}_R^{-1}\mathbf{v}\|_{1,\Omega}^2 \leq \langle \mathbf{S}\mathbf{S}_R^{-1}\mathbf{v}, \mathbf{S}_R^{-1}\mathbf{v} \rangle \\ &= \langle \mathbf{v}, \mathbf{S}_R^{-1}\mathbf{v} \rangle_{0,\Omega} \leq \|\mathbf{v}\|_{0,\Omega} \|\mathbf{S}_R^{-1}\mathbf{v}\|_{0,\Omega}. \end{aligned}$$

Moreover, for a generalized eigenvalue $\omega^2 \neq 0$ and a corresponding eigenfunction $\mathbf{u} \in \mathbf{V}$ of \mathbf{S} , the operator \mathbf{S}_R^{-1} satisfies the inverse eigenvalue problem

$$\mathbf{S}_R^{-1}\mathbf{u} = \frac{1}{\omega^2} \mathbf{u}. \quad (27)$$

On the other hand, if $\mathbf{u} \in \mathbf{L}^2(\Omega)$ satisfies (27), then $\mathbf{u} \in \mathbf{V}$ (since $\mathbf{S}_R^{-1}(\mathbf{L}^2(\Omega)) \subset \mathbf{V}$) and \mathbf{u} is an eigenfunction of \mathbf{S} . The operator \mathbf{S}_R^{-1} is compact, since the embedding $\mathbf{V} \subset \mathbf{L}^2(\Omega)$ is compact. Consequently, \mathbf{S}_R^{-1} is a compact self-adjoint endomorphism on $\mathbf{L}^2(\Omega)$ and hence, in view of (26), the assertions can be deduced from the Hilbert-Schmidt theory and the Fredholm alternative (cf., e.g., [60]). \square

Theorem 4.1 tells us that the solvability of the Schur complement system (21) is guaranteed for almost all $\omega^2 \in \mathbb{R}$. If ω^2 is a generalized eigenvalue of \mathbf{S} , the solvability condition c) is in fact a condition on the boundary data, since $\mathbf{F} = \mathbf{f} + \mathbf{B}\mathbf{C}^{-1}g$ and by (20),

$$\mathbf{F} = \mathbf{R}_{\Gamma_\sigma}^*(\boldsymbol{\sigma}_n) + \mathbf{B}\mathbf{C}^{-1}\mathbf{R}_{\Gamma_D}^*D_n - (\mathbf{S} - \omega^2\mathbf{I})\mathbf{E}_{\Gamma_u}(\mathbf{u}_\Gamma).$$

Remark 4.1 (A 2.5 D Model). SAWs propagate along the surface of a substrate. To be more precise, the amplitude of the displacement \mathbf{u} decays exponentially with the depth of the penetration into the substrate [35]. In true Rayleigh waves, most of the energy (90%) is concentrated within one wavelength from the surface. If h is the height of the substrate with the surface located at $x_3 = 0$, this leads to the definition

$$H(x_3) := \frac{1 - e^{-\frac{\alpha(x_3+h)}{h}}}{1 - e^{-\alpha}}. \quad (28)$$

We reduce the dependency on x_3 to exponential decay:

$$\mathbf{u}(\mathbf{x}) = H(x_3)\mathbf{u}(x_1, x_2), \quad (29)$$

$$\Phi(\mathbf{x}) = H(x_3)\Phi(x_1, x_2). \quad (30)$$

The factor α measures the rapidity of the exponential decay. A good guess for this parameter can be obtained from 2D calculations.

5 Finite element approximation of the surface acoustic wave equations

We now restrict ourselves to the case where the computational domain $\Omega \subset \mathbb{R}^d$ is a polygonal resp. polyhedral domain. We provide a simplicial triangulation $\mathcal{T}_h(\Omega)$ of Ω that aligns with Γ_u and Γ_ϕ and denote by $S_{0,\Gamma'}^{(k)}(\Omega; \mathcal{T}_h(\Omega))$, $k \in \mathbb{N}$, $\Gamma' = \Gamma_u$ or $\Gamma' = \Gamma_\phi$ the finite element space of continuous functions $v_h : \Omega \rightarrow \mathbb{C}$ vanishing on Γ' and satisfying $v_h|_T \in P_k(T)$, $T \in \mathcal{T}_h(\Omega)$, where $P_k(T)$ stands for the linear space of complex valued polynomials of degree k on $T \in \mathcal{T}_h(\Omega)$. We approximate the space \mathbf{V} of displacements and the space W of electric potentials by

$$\mathbf{V}_h := S_{0,\Gamma_u}^{(k)}(\Omega; \mathcal{T}_h(\Omega))^d, \quad (31a)$$

$$W_h := S_{0,\Gamma_\phi}^{(k)}(\Omega; \mathcal{T}_h(\Omega)). \quad (31b)$$

We refer to $\mathbf{A}_h : \mathbf{V}_h \rightarrow \mathbf{V}_h^*$, $\mathbf{B}_h : W_h \rightarrow \mathbf{V}_h^*$ and $\mathbf{C}_h : W_h \rightarrow W_h^*$ as the operators associated with the sesquilinear forms $a(\cdot, \cdot)$, $b(\cdot, \cdot)$ and $c(\cdot, \cdot)$ when restricted to the

respective finite dimensional subspaces, i.e., $a|_{\mathbf{V}_h \times \mathbf{V}_h}$, $b|_{W_h \times \mathbf{V}_h}$, and $c|_{W_h \times W_h}$. We note that these operators inherit their properties from its continuous counterparts. In particular, \mathbf{A}_h , \mathbf{B}_h and \mathbf{C}_h are bounded linear operators. Moreover, the operator \mathbf{A}_h is symmetric and \mathbf{V}_h -elliptic, whereas \mathbf{C}_h is symmetric and W_h -elliptic having the same ellipticity constants γ_A and γ_C . We further define $\mathbf{f}_h \in \mathbf{V}_h^*$ and $g_h \in W_h^*$ by $\langle \mathbf{f}_h, \mathbf{u}_h \rangle := \langle \mathbf{f}, \mathbf{u}_h \rangle$, $\mathbf{u}_h \in \mathbf{V}_h$, and $\langle g_h, \Phi_h \rangle := \langle g, \Phi_h \rangle$, $\Phi_h \in W_h$.

The finite element approximation of (19) amounts now to the computation of $\mathbf{u}_h \in \mathbf{V}_h$ and $\Phi_h \in W_h$ such that

$$\begin{aligned} (\mathbf{A}_h - \omega^2\mathbf{I}_h)\mathbf{u}_h + \mathbf{B}_h\Phi_h &= \mathbf{f}_h, \\ \mathbf{B}_h^*\mathbf{u}_h - \mathbf{C}_h\Phi_h &= g_h, \end{aligned} \quad (32)$$

where \mathbf{I}_h is the injection $\mathbf{I}_h : \mathbf{V}_h \rightarrow \mathbf{V}_h^*$.

Again, static condensation of Φ_h yields the discrete Schur complement system

$$(\mathbf{S}_h - \omega^2\mathbf{I}_h)\mathbf{u}_h = \mathbf{F}_h \quad (33)$$

with $\mathbf{F}_h := \mathbf{f}_h + \mathbf{B}_h\mathbf{C}_h^{-1}g_h$ and the discrete Schur complement operator \mathbf{S}_h given by

$$\mathbf{S}_h := \mathbf{A}_h + \mathbf{B}_h\mathbf{C}_h^{-1}\mathbf{B}_h^*. \quad (34)$$

It is an easy exercise to show that \mathbf{S}_h as given by (34) is indeed the Galerkin approximation of \mathbf{S} , i.e.,

$$\langle \mathbf{S}_h\mathbf{v}_h, \mathbf{w}_h \rangle = \langle \mathbf{S}\mathbf{v}_h, \mathbf{w}_h \rangle, \mathbf{v}_h, \mathbf{w}_h \in \mathbf{V}_h.$$

If $\omega \in \mathbb{R}$ is such that (21) is solvable, then it is well-known that the operator $\mathbf{S}_\omega := \mathbf{S} - \omega^2\mathbf{I}$ satisfies the inf-sup condition (cf., e.g., [12])

$$\inf_{\mathbf{0} \neq \mathbf{v} \in \mathbf{V}} \sup_{\mathbf{0} \neq \mathbf{w} \in \mathbf{V}} \frac{|\langle \mathbf{S}_\omega\mathbf{v}, \mathbf{w} \rangle|}{\|\mathbf{v}\|_{1,\Omega}\|\mathbf{w}\|_{1,\Omega}} \geq \beta > 0. \quad (35)$$

As has been shown in [31], for sufficiently small h a discrete inf-sup condition holds true as well:

Theorem 5.1. *Let \mathbf{S}_h be given by (34) and assume that for some $\omega \in \mathbb{R}$ the operator \mathbf{S}_ω satisfies the inf-sup condition (35). Then, there exist $h_0 > 0$ and $\beta_{min} > 0$ such that for all $h \leq h_0$ the operator $\mathbf{S}_{h,\omega} := \mathbf{S}_h - \omega^2\mathbf{I}_h$ satisfies the discrete inf-sup condition*

$$\inf_{\mathbf{0} \neq \mathbf{v}_h \in \mathbf{V}_h} \sup_{\mathbf{0} \neq \mathbf{w}_h \in \mathbf{V}_h} \frac{|\langle \mathbf{S}_{h,\omega}\mathbf{v}_h, \mathbf{w}_h \rangle|}{\|\mathbf{v}_h\|_{1,\Omega}\|\mathbf{w}_h\|_{1,\Omega}} \geq \beta_h \geq \beta_{min}.$$

Proof. We give the proof for completeness and assume without restriction of generality that $\omega \neq 0$. We introduce bounded linear operators $\mathbf{S}^{-1} : \mathbf{V} \rightarrow \mathbf{V}$ and $\mathbf{S}_h^{-1} : \mathbf{V}_h \rightarrow \mathbf{V}_h$ by $\mathbf{S}(\mathbf{S}^{-1}\mathbf{v}) = \mathbf{I}\mathbf{v}$, $\mathbf{v} \in \mathbf{V}$, and $\mathbf{S}_h(\mathbf{S}_h^{-1}\mathbf{v}_h) = \mathbf{I}_h\mathbf{v}_h$, $\mathbf{v}_h \in \mathbf{V}_h$. Taking (35) into account, for $\mathbf{v} \in \mathbf{V}$ we then get

$$\begin{aligned} \beta\|\mathbf{v}\|_{1;\Omega} &\leq \sup_{\mathbf{0} \neq \mathbf{w} \in \mathbf{V}} \frac{|\langle \mathbf{S}_\omega\mathbf{v}, \mathbf{w} \rangle|}{\|\mathbf{w}\|_{1;\Omega}} = \\ &= \sup_{\mathbf{0} \neq \mathbf{w} \in \mathbf{V}} \frac{|\langle \mathbf{S}(\mathbf{v} - \omega^2\mathbf{S}^{-1}\mathbf{v}), \mathbf{w} \rangle|}{\|\mathbf{w}\|_{1;\Omega}} \\ &\leq \|\mathbf{S}\|\|\mathbf{v} - \omega^2\mathbf{S}^{-1}\mathbf{v}\|_{1;\Omega}. \end{aligned}$$

Hence, in view of the V_h -ellipticity of S_h for $\mathbf{v}_h \in V_h$ we obtain

$$\begin{aligned} & \sup_{\mathbf{0} \neq \mathbf{w}_h \in V_h} \frac{|\langle S_{h,\omega} \mathbf{v}_h, \mathbf{w}_h \rangle|}{\|\mathbf{w}_h\|_{1;\Omega}} = \\ &= \sup_{\mathbf{0} \neq \mathbf{w}_h \in V_h} \frac{|\langle S_h(\mathbf{v}_h - \omega^2 S_h^{-1} \mathbf{v}_h), \mathbf{w}_h \rangle|}{\|\mathbf{w}_h\|_{1;\Omega}} \\ &\geq \frac{|\langle S_h(\mathbf{v}_h - \omega^2 S_h^{-1} \mathbf{v}_h), \mathbf{v}_h - \omega^2 S_h^{-1} \mathbf{v}_h \rangle|}{\|\mathbf{v}_h - \omega^2 S_h^{-1} \mathbf{v}_h\|_{1;\Omega}} \\ &\geq \gamma_S \|\mathbf{v}_h - \omega^2 S_h^{-1} \mathbf{v}_h\|_{1;\Omega} \\ &\geq \gamma_S \|\mathbf{v}_h - \omega^2 S^{-1} \mathbf{v}_h\|_{1;\Omega} - \omega^2 \gamma_S \|(\mathbf{S}_h^{-1} - \mathbf{S}^{-1}) \mathbf{v}_h\|_{1;\Omega} \\ &\geq \left(\frac{\beta \gamma_S}{\|\mathbf{S}\|} - \omega^2 \gamma_S \|\mathbf{S}_h^{-1} - \mathbf{S}^{-1}\| \right) \|\mathbf{v}_h\|_{1;\Omega} \end{aligned}$$

whence

$$\beta_h \geq \frac{\beta \gamma_S}{\|\mathbf{S}\|} - \omega^2 \gamma_S \|\mathbf{S}_h^{-1} - \mathbf{S}^{-1}\|.$$

Since $\|\mathbf{S}_h^{-1} - \mathbf{S}^{-1}\| \rightarrow 0$ as $h \rightarrow 0$, we conclude. \square

6 Multilevel preconditioned iterative solution of the saddle point system

The discrete system (32) represents an algebraic saddle point problem of the form

$$\begin{pmatrix} \mathbf{A} & \mathbf{B} \\ \mathbf{B}^T & -\mathbf{C} \end{pmatrix} \begin{pmatrix} \mathbf{u} \\ \boldsymbol{\Phi} \end{pmatrix} = \begin{pmatrix} \mathbf{f} \\ \mathbf{g} \end{pmatrix} \quad \text{or} \quad \mathbf{Z}\mathbf{U} = \boldsymbol{\ell}. \quad (36)$$

Here, $\mathbf{A} \in \mathbb{R}^{n \times n}$ and $\mathbf{C} \in \mathbb{R}^{m \times m}$ are symmetric, positive definite matrices satisfying

$$\gamma_1 \mathbf{v}^T \mathbf{v} \leq \mathbf{v}^T \mathbf{A} \mathbf{v} \leq \Gamma_1 \mathbf{v}^T \mathbf{v}, \quad \mathbf{v} \in \mathbb{R}^n, \quad (37a)$$

$$\gamma_2 \boldsymbol{\Phi}^T \boldsymbol{\Phi} \leq \boldsymbol{\Phi}^T \mathbf{C} \boldsymbol{\Phi} \leq \Gamma_2 \boldsymbol{\Phi}^T \boldsymbol{\Phi}, \quad \boldsymbol{\Phi} \in \mathbb{R}^m \quad (37b)$$

with constants $0 < \gamma_i \leq \Gamma_i, 1 \leq i \leq 2$. Moreover, $\mathbf{B} \in \mathbb{R}^{n \times m}$ and $\mathbf{f} \in \mathbb{R}^n, \mathbf{g} \in \mathbb{R}^m$ whence $\mathbf{Z} \in \mathbb{R}^{N \times N}, \boldsymbol{\ell} \in \mathbb{R}^N$ where $N := n + m$. We further assume that \mathbf{Z} satisfies

$$\inf_{\mathbf{U} \neq \mathbf{0}} \sup_{\mathbf{V} \neq \mathbf{0}} \frac{|\mathbf{V}^T \mathbf{Z} \mathbf{U}|}{\|\mathbf{U}\| \|\mathbf{V}\|} \geq \gamma_Z > 0, \quad (38)$$

where $\|\cdot\|$ stands for the Euclidean norm in \mathbb{R}^N .

Generalized saddle point problems such as (36) arise in many applications as, for instance, in the framework of stabilized Stokes systems [49, 50] or in mixed finite element approximations of boundary value problems for elliptic equations and systems [12]. We refer to [7, 15, 38] and to the references therein for basic results and to [5, 10, 14, 17, 25, 26, 31, 32] for efficient iterative solution techniques including multilevel preconditioning.

In the sequel, we closely follow [32, 50] and consider block-diagonal preconditioners of the form

$$\mathbf{P}^{-1} := \begin{pmatrix} \tilde{\mathbf{A}} & \mathbf{0} \\ \mathbf{0} & \tilde{\mathbf{C}} \end{pmatrix}, \quad (39)$$

where we assume that $\tilde{\mathbf{A}} \in \mathbb{R}^{n \times n}$ and $\tilde{\mathbf{C}} \in \mathbb{R}^{m \times m}$ are symmetric, positive definite matrices satisfying

$$\tilde{\gamma}_1 \mathbf{v}^T \mathbf{v} \leq \mathbf{v}^T \tilde{\mathbf{A}} \mathbf{v} \leq \tilde{\Gamma}_1 \mathbf{v}^T \mathbf{v}, \quad \mathbf{v} \in \mathbb{R}^n, \quad (40a)$$

$$\tilde{\gamma}_2 \boldsymbol{\Phi}^T \boldsymbol{\Phi} \leq \boldsymbol{\Phi}^T \tilde{\mathbf{C}} \boldsymbol{\Phi} \leq \tilde{\Gamma}_2 \boldsymbol{\Phi}^T \boldsymbol{\Phi}, \quad \boldsymbol{\Phi} \in \mathbb{R}^m \quad (40b)$$

with constants $0 < \tilde{\gamma}_i \leq \tilde{\Gamma}_i, 1 \leq i \leq 2$.

As an easy consequence from (40) we deduce that \mathbf{P}^{-1} is positive definite with

$$\Gamma_P^{-1} \mathbf{z}^T \mathbf{z} \leq \mathbf{z}^T \mathbf{P}^{-1} \mathbf{z} \leq \gamma_P^{-1} \mathbf{z}^T \mathbf{z}, \quad \mathbf{z} \in \mathbb{R}^N, \quad (41)$$

where $\gamma_P^{-1} := \max(\tilde{\Gamma}_1, \tilde{\Gamma}_2)$ and $\Gamma_P^{-1} := 1/(\min(\tilde{\gamma}_1, \tilde{\gamma}_2))$.

Using (38) and (41), we can readily derive lower and upper bounds for the spectrum of the preconditioned matrix $\mathbf{P}^{\frac{1}{2}} \mathbf{Z} \mathbf{P}^{\frac{1}{2}}$:

Theorem 6.1. *Suppose that (38) and (41) are satisfied for \mathbf{Z} and \mathbf{P}^{-1} , respectively. Then, for $\mathbf{V} \in \mathbb{R}^N$ there holds*

$$\gamma_{PZ} \mathbf{V}^T \mathbf{V} \leq \mathbf{V}^T \mathbf{P}^{\frac{1}{2}} \mathbf{Z} \mathbf{P}^{\frac{1}{2}} \mathbf{V} \leq \Gamma_{PZ} \mathbf{V}^T \mathbf{V}, \quad (42)$$

where $\gamma_{PZ} := \gamma_P \gamma_Z$ and $\Gamma_{PZ} := \Gamma_P \|\mathbf{Z}\|$.

Proof. Straightforward computations yield

$$\begin{aligned} & \inf_{\mathbf{W} \neq \mathbf{0}} \sup_{\mathbf{V} \neq \mathbf{0}} \frac{\mathbf{V}^T \mathbf{P}^{\frac{1}{2}} \mathbf{Z} \mathbf{P}^{\frac{1}{2}} \mathbf{W}}{\|\mathbf{V}\| \|\mathbf{W}\|} = \\ &= \inf_{\tilde{\mathbf{W}} \neq \mathbf{0}} \sup_{\tilde{\mathbf{V}} \neq \mathbf{0}} \frac{\tilde{\mathbf{V}}^T \mathbf{Z} \tilde{\mathbf{W}}}{(\tilde{\mathbf{V}}^T \mathbf{P}^{-1} \tilde{\mathbf{V}})^{\frac{1}{2}} (\tilde{\mathbf{W}}^T \mathbf{P}^{-1} \tilde{\mathbf{W}})^{\frac{1}{2}}} \geq \\ &\geq \gamma_P \inf_{\tilde{\mathbf{W}} \neq \mathbf{0}} \sup_{\tilde{\mathbf{V}} \neq \mathbf{0}} \frac{\tilde{\mathbf{V}}^T \mathbf{Z} \tilde{\mathbf{W}}}{\|\tilde{\mathbf{V}}\| \|\tilde{\mathbf{W}}\|} \geq \gamma_P \gamma_Z. \end{aligned}$$

Similar arguments result in the upper bound in (42). \square

We allow the following inf-sup condition for the sesquilinear form $b(\cdot, \cdot)$ restricted to $V_h \times W_h$:

$$\inf_{\mathbf{v}_h \in V_h} \sup_{\varphi_h \in W_h} \frac{|b(\mathbf{v}_h, \varphi_h)|}{\|\mathbf{v}_h\|_{\mathbf{V}} \|\varphi_h\|_{\mathbf{W}}} \geq \beta_h \geq \beta_{\min} \geq 0, \quad (43)$$

i.e., $\beta_{\min} = 0$ is admitted. In this case, the associated matrix \mathbf{B} may have a non-trivial kernel, and we get:

Lemma 6.1. *Under the assumptions (37b) and (43), for $\mathbf{v} \in \mathbb{R}^n, \mathbf{v} \neq \mathbf{0}$ there holds*

$$\frac{\beta_{\min}^2}{\|\mathbf{C}\|} \leq \frac{\mathbf{v}^T \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{v}}{\mathbf{v}^T \mathbf{v}} \leq \frac{\|\mathbf{B}\|^2}{\gamma_2}. \quad (44)$$

Proof. For $\mathbf{v} \in \mathbb{R}^n$ we readily obtain

$$\begin{aligned} \mathbf{v}^T \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{v} &= \sup_{\boldsymbol{\Phi} \neq \mathbf{0}} \frac{(\boldsymbol{\Phi}^T \mathbf{C} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{v})^2}{\boldsymbol{\Phi}^T \mathbf{C} \boldsymbol{\Phi}} \\ &\geq \frac{1}{\|\mathbf{C}\|} \frac{(\boldsymbol{\Phi}^T \mathbf{B} \mathbf{v})^2}{\boldsymbol{\Phi}^T \boldsymbol{\Phi}} \geq \frac{\beta_{\min}^2}{\|\mathbf{C}\|} \mathbf{v}^T \mathbf{v} \end{aligned}$$

and

$$\mathbf{v}^T \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{v} \leq \frac{1}{\gamma_2} \|\mathbf{B}^T \mathbf{v}\|^2 \leq \frac{\|\mathbf{B}\|^2}{\gamma_2} \mathbf{v}^T \mathbf{v}. \quad \square$$

The preconditioned saddle point system is given by

$$\begin{pmatrix} \tilde{\mathbf{A}}^{-1} \mathbf{A} & \tilde{\mathbf{A}}^{-1} \mathbf{B} \\ \tilde{\mathbf{C}}^{-1} \mathbf{B}^T & -\tilde{\mathbf{C}}^{-1} \mathbf{C} \end{pmatrix} \begin{pmatrix} \mathbf{u} \\ \Phi \end{pmatrix} = \begin{pmatrix} \tilde{\mathbf{A}}^{-1} \mathbf{f} \\ \tilde{\mathbf{C}}^{-1} \mathbf{g} \end{pmatrix}. \quad (45)$$

A simple computation shows that the Schur complement matrix of the preconditioned system is given by

$$\tilde{\mathbf{S}} = \tilde{\mathbf{A}}^{-1} \mathbf{S},$$

thus completely neglecting the dependence on the preconditioner part $\tilde{\mathbf{C}}^{-1}$. This is immediately clear, since this preconditioner only speeds up the inner iteration when solving systems with coefficient matrix \mathbf{C} . The spectrum of $\tilde{\mathbf{A}}^{-1} \mathbf{S}$ can be determined from the eigenvalues of $\tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{S} \tilde{\mathbf{A}}^{-\frac{1}{2}}$.

Theorem 6.2. *For the spectrum of $\tilde{\mathbf{S}}$ we have the following lower and upper bound*

$$\gamma_{PS} \leq \frac{\mathbf{v}^T \tilde{\mathbf{S}} \mathbf{v}}{\|\mathbf{v}\|^2} \leq \Gamma_{PS}, \quad (46)$$

where

$$\gamma_{PS} := \frac{1}{\|\tilde{\mathbf{A}}\|} \left(\gamma_1 + \frac{\beta_{\min}^2}{\|\mathbf{C}\|} \right), \quad (47)$$

$$\Gamma_{PS} := \frac{1}{\tilde{\gamma}_1} \left(\|\mathbf{A}\| + \frac{\|\mathbf{B}\|^2}{\gamma_2} \right). \quad (48)$$

Proof. Setting $\mathbf{w} := \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{v}$, we obtain

$$\begin{aligned} \frac{\mathbf{v}^T \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{S} \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{v}}{\mathbf{v}^T \mathbf{v}} &= \\ &= \frac{\mathbf{v}^T \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{A} \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{v}}{\mathbf{v}^T \mathbf{v}} + \frac{\mathbf{v}^T \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \tilde{\mathbf{A}}^{-\frac{1}{2}} \mathbf{v}}{\mathbf{v}^T \mathbf{v}} \\ &= \frac{\mathbf{w}^T \mathbf{A} \mathbf{w}}{\mathbf{w}^T \tilde{\mathbf{A}} \mathbf{w}} + \frac{\mathbf{w}^T \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{w}}{\mathbf{w}^T \tilde{\mathbf{A}} \mathbf{w}}. \end{aligned}$$

The first term can be estimated by the ellipticity properties of \mathbf{A} and $\tilde{\mathbf{A}}$,

$$\frac{\gamma_1}{\|\tilde{\mathbf{A}}\|} \leq \frac{\mathbf{w}^T \mathbf{A} \mathbf{w}}{\mathbf{w}^T \tilde{\mathbf{A}} \mathbf{w}} \leq \frac{\|\mathbf{A}\|}{\tilde{\gamma}_1}.$$

By Lemma 6.1 and the ellipticity property of $\tilde{\mathbf{A}}$, for the second term it follows that

$$\frac{\beta_{\min}^2}{\|\tilde{\mathbf{A}}\| \|\mathbf{C}\|} \leq \frac{\mathbf{w}^T \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^T \mathbf{w}}{\mathbf{w}^T \tilde{\mathbf{A}} \mathbf{w}} \leq \frac{\|\mathbf{B}\|^2}{\tilde{\gamma}_1 \gamma_2}.$$

Combining both estimates, gives the assertion. \square

We are particularly interested in such preconditioners where the lower and upper bounds γ_{PZ} and Γ_{PZ} for the spectrum of the preconditioned saddle point matrix \mathbf{PZ} and the corresponding bounds γ_{PS} and Γ_{PS} for the spectrum of the preconditioned Schur complement $\tilde{\mathbf{A}}^{-1} \mathbf{S}$ as well as the bounds for the spectrum of $\tilde{\mathbf{C}}^{-1} \mathbf{C}$ are independent of the granularity h of the triangulations. Such preconditioners are provided by multilevel preconditioners of BPX-type with respect to a nested hierarchy of simplicial triangulations of the computational domain Ω (cf., e.g., [11, 41]).

7 Numerical Results

In this section, we present a documentation of numerical results both for a test problem in order to study the performance of the block-diagonally preconditioned iterative solver of the finite element discretized surface acoustic wave equations and for a realistic surface acoustic wave device as it is used on microfluidic biochips. The solver is implemented within the finite element toolbox ALBERTA [47, 48].

7.1 Test Problem

For the test problem, we assume that, in Voigt notation, the elasticity tensor $\mathbf{c} = (c_{IK})$ and the piezoelectric tensor $\mathbf{e} = (e_{IK})$ are given by

$$\mathbf{c} = \begin{pmatrix} 20 & 5 & 7 & 1 & 0 & 0 \\ 5 & 20 & 7 & -1 & 0 & 0 \\ 7 & 7 & 25 & 0 & 0 & 0 \\ -1 & -1 & 0 & 5 & 0 & 0 \\ 0 & 0 & 0 & 0 & 6 & 1 \\ 0 & 0 & 0 & 0 & 1 & 7 \end{pmatrix},$$

$$\mathbf{e} = \begin{pmatrix} -4 & 1 & 1 & 0 & 0 & 0 \\ 0 & -4 & 1 & 0 & 0 & 0 \\ 1 & 1 & 1 & 1 & 1 & 1 \end{pmatrix},$$

whereas the dielectric tensor $\epsilon = (\epsilon_{ij})$ is chosen according to

$$\epsilon = \begin{pmatrix} 10 & 0 & 0 \\ 0 & 10 & 0 \\ 0 & 0 & 5 \end{pmatrix}.$$

We note that the material moduli resemble the properties of a typical piezoelectric material like quartz.

The right-hand sides and boundary data are chosen in such a way that

$$\mathbf{u}(\mathbf{x}) = \mathbf{x}^T \mathbf{x} (1, 2, 3)^T, \quad \Phi(\mathbf{x}) = \sum_{i=1}^3 \sin(\pi x_i),$$

solves the time-harmonic surface acoustic wave equations (11), (12) and (15) for angular frequencies ω ranging between $\omega = 0$ and $\omega = 25$.

We apply the iterative solvers GMRES and BICGSTAB with and without the block-diagonal preconditioners to the algebraic saddle point problems arising from finite element discretizations with respect to uniform hierarchies of simplicial triangulations of the computational domain in its non-symmetric formulation

$$\begin{pmatrix} \mathbf{A}_\omega & \mathbf{B} \\ -\mathbf{B}^T & \mathbf{C} \end{pmatrix} \begin{pmatrix} \mathbf{u} \\ \Phi \end{pmatrix} = \begin{pmatrix} \mathbf{f} \\ -\mathbf{g} \end{pmatrix},$$

where $\mathbf{A}_\omega := \mathbf{A} - \omega^2 \mathbf{I}$. We also consider the iterative solution of the Schur complement system

$$\begin{aligned} \mathbf{S} \mathbf{u} &= (\mathbf{A}_\omega + \mathbf{B} \mathbf{C}^{-1} \mathbf{B}^*) \mathbf{u} = \mathbf{F}, \\ \mathbf{C} \Phi &= \mathbf{C} \mathbf{u} - \mathbf{g} \end{aligned}$$

by the CG method with and without preconditioning (SC-CG/SC-PCG).

We first consider the results of a 2D simulation where $\Omega = (-1, +1)^2$ and the boundaries $\Gamma_u, \Gamma_\sigma, \Gamma_\phi$ and Γ_D are given as follows

$$\begin{aligned}\Gamma_u &:= [-1, +1] \times \{-1\} \cup \{+1\} \times [-1, +1], \\ \Gamma_\sigma &:= (-1, +1) \times \{+1\} \cup \{-1\} \times (-1, +1), \\ \Gamma_\phi &:= [-1, +1] \times \{-1\} \cup \{-1\} \times [-1, +1], \\ \Gamma_D &:= (-1, +1) \times \{+1\} \cup \{+1\} \times (-1, +1).\end{aligned}$$

The stopping criterion for the iterations has been chosen such that the residual gets smaller than 10^{-6} . We list the number of iterations for SC-CG, GMRES and BICGSTAB with and without preconditioner. Since the effort for one iteration step is not directly comparable (there is an inner iteration in the application of the Schur complement), we have also measured the CPU-time (in seconds). Table 7.1 and Table 7.1 contain the results without and with the BPX-type preconditioner:

Table 1. Number of iterations and CPU-time (in seconds) for SC-CG and BICGSTAB/GMRES without preconditioner

Level	SC-CG		BICGSTAB		GMRES	
	time	iter	time	iter	time	iter
3	0.15	74	0.10	65	0.14	17
4	1.4	148	0.75	137	1.7	56
5	29	311	7.6	324	32	206
6	440	872	75	678	530	758

Table 2. Number of iterations and CPU-time (in seconds) for SC-PCG and BICGSTAB/GMRES with preconditioner

Level	SC-PCG		PBICGSTAB		PGMRES	
	time	iter	time	iter	time	iter
5	2.5	48	1.1	33	1.2	6
6	12	52	5.2	39	5.9	7
7	70	55	23	41	25	7
8	290	57	92	44	100	8

Using no preconditioning, BICGSTAB has clearly outperformed SC-CG and GMRES in terms of CPU-time and iterations. Applying the BPX-type preconditioner, PBICGSTAB and PGMRES perform similarly and both outclass SC-PCG. We have also performed 3D simulations for the computational domain $\Omega = (-1, +1)^3$ and the boundaries $\Gamma_u, \Gamma_\sigma, \Gamma_\phi$, and Γ_D specified according to

$$\begin{aligned}\Gamma_u &:= [-1, +1]^2 \times \{-1\}, \quad \Gamma_\sigma := \partial\Omega \setminus \Gamma_u, \\ \Gamma_\phi &:= \{-1\} \times [-1, +1]^2, \quad \Gamma_D := \partial\Omega \setminus \Gamma_\phi.\end{aligned}$$

Using the same termination criterion, the performance of SC-CG, BI-CGSTAB and GMRES with and without preconditioning was roughly the same as in the 2D case.

In order to illustrate the dependence of SC-CG and SC-PCG on the refinement level, Figure 9 displays the number of iterations as a function of the refinement level ℓ for SC-CG (blue line) and SC-PCG with the BPX preconditioner (red line). For comparison, the results for SC-PCG with the hierarchical type preconditioner (cf., e.g., [41, 59]) are shown as well (green line). The results clearly show the exponential growth of the condition number of SC-PCG in ℓ and the level independence of SC-PCG with the BPX preconditioner at least in 2D (in the 3D case the asymptotics has not yet been reached). Likewise, the theoretically predicted growth of the condition number like $O((\ell + 1)^2)$ for $d = 2$ and like $O(2^\ell)$ for $d = 3$ of SC-PCG with the hierarchical type preconditioner is reflected by the numerical results as well.

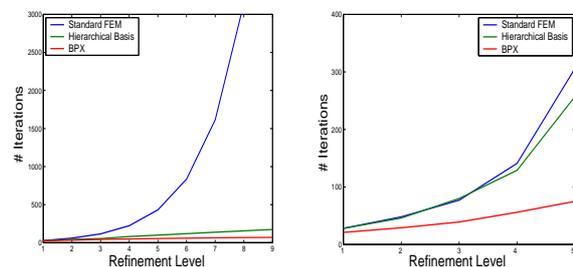


Fig. 9. Number of iterations required to reach a fixed tolerance $TOL = 10^{-6}$; 2D simulation (left) and 3D simulation (right)

7.2 Surface Acoustic Wave Device Simulation

The piezoelectric material used for the SAW chip in our calculations is lithium niobate (LiNbO_3). Usually, one is interested in very large monocrystals appearing only randomly in nature. However, sophisticated production procedures for all technologically relevant materials are at hand. Depending on the cut used for the special device the monocrystals are sawed. For details concerning production procedures, natural appearances and the material constants stated here we refer to [61] and the references therein.

The material moduli are given here in a way such that the coordinate x_3 -axis is identical with the polar axis Z along which rotatory polarization occurs (the crystallographic Z -axis). By convention, the crystallographic axes are denoted by X, Y, Z , while the coordinate axes are denoted x_1, x_2, x_3 .

Lithium niobate is an extremely versatile crystal material. It possesses a very high Curie temperature and excellent piezoelectric coupling coefficient making it attractive for ultrasonic device applications. Lithium niobate possesses a number of useful cuts that are extensively used in transducer applications, e.g. YZ LiNbO_3 (i.e. Y -axis crystal cut, Z -axis propagation) or 128° rotated YX LiNbO_3 . Material moduli are given for room temperature (20°C) in the following table:

Table 3. Material Moduli for 128° rotated YX LiNbO₃ (note that $c_{11} = c_{22}, c_{13} = c_{23}, c_{14} = -c_{24} = c_{56}, c_{44} = c_{55}$ and $e_{22} = -e_{16}$)

c [$10^{10} \frac{N}{m^2}$]	c_{11}	c_{12}	c_{13}	c_{14}	c_{33}	c_{44}	c_{66}
	20.3	5.3	7.5	0.9	24.5	6.0	7.5
e [$\frac{C}{m^2}$]	$e_{15} = e_{24}$		$e_{22} = -e_{21}$		$e_{31} = e_{32}$		e_{33}
	3.7		2.5		0.1		1.3
ϵ [$10^{-12} \frac{F}{m}$]	$\epsilon_{11} = \epsilon_{22}$				ϵ_{33}		
	749.0				253.2		

The constants given here are for crystal geometries coinciding with the coordinate planes. For some technological reasons, different cuts of crystals are preferred in practice, i.e. a coordinate transformation is realized by

$$\bar{\mathbf{x}} = \bar{\mathbf{x}}(\mathbf{x}),$$

The material moduli in the new coordinate system are then regained by the tensor transformations

$$\bar{c}_{\bar{i}\bar{j}\bar{k}\bar{l}} = c_{ijkl} \frac{\partial \bar{x}_{\bar{i}}}{\partial x_i} \frac{\partial \bar{x}_{\bar{j}}}{\partial x_j} \frac{\partial \bar{x}_{\bar{k}}}{\partial x_k} \frac{\partial \bar{x}_{\bar{l}}}{\partial x_l}, \quad (50)$$

$$\bar{e}_{\bar{i}\bar{j}\bar{k}} = e_{ijk} \frac{\partial \bar{x}_{\bar{i}}}{\partial x_i} \frac{\partial \bar{x}_{\bar{j}}}{\partial x_j} \frac{\partial \bar{x}_{\bar{k}}}{\partial x_k}, \quad (51)$$

$$\bar{\epsilon}_{\bar{i}\bar{j}} = \epsilon_{ij} \frac{\partial \bar{x}_{\bar{i}}}{\partial x_i} \frac{\partial \bar{x}_{\bar{j}}}{\partial x_j}. \quad (52)$$

Usually, a simple rigid rotation is undertaken, i.e. the coordinate transformation is linear, $\bar{\mathbf{x}} = \mathbf{T}\mathbf{x}$, and $\frac{\partial \bar{x}_{\bar{i}}}{\partial x_i} = T_{\bar{i}i}$ represent the direction cosines between the two frames of reference.

In this setting, the relationship between the crystallographic fundamental orthogonal system of axes X, Y, Z and the coordinate axes x_1, x_2, x_3 must be known. Note, that there are piezoelectric materials where the orientations of the crystallographic unit cell axes do not align with the fundamental coordinate system, but usually constants are given for the fundamental coordinate system and we will not consider such materials anyway.

In transducer design, there is a simple standardized [27] way to provide this information: Here, the first two letters (out of X, Y, Z) denote the initial plate orientation, the first indicating the plate thickness, the second the plate length before any rotations. The remaining three symbols ($t =$ thickness, $w =$ width, $l =$ length) are used to indicate the plate edges used for rotation, followed by a list of corresponding angles (see Figure 10 (left) for a YZ -plate and Figure 10 (right) for a rotated $YZw - \phi$ plate).

For the surface acoustic wave device, we have used a reduced model in the (x_1, x_3) -plane assuming that all variables do not depend on x_2 and have no impact in the x_2 -direction. The piezoelectric material is lithium niobate (LiNbO₃) with density $\rho = 4630 \frac{kg}{m^3}$. This chip is operated at room temperature ($20^\circ C$). We remark that

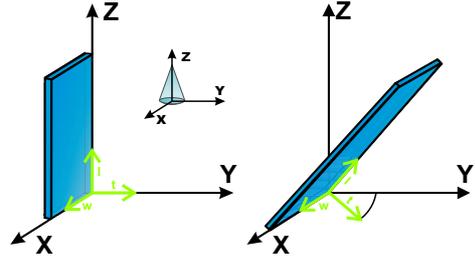


Fig. 10. Piezoelectric plate in crystallographic X, Y, Z coordinate system; YZ orientation (left) and $YZw - \phi$ orientation (right)

the SAW devices can be cooled efficiently. Hence, the assumption of a constant operating temperature is justified. The used crystal cut is YXl 128° LiNbO₃. The length ℓ and the height h of the SAW chip have been chosen according to $\ell = 1.2\text{mm}$ and $h = 0.6\text{mm}$ so that $\Omega = (0, 1.2) \times (0, 0.6)$. The Dirichlet and Neumann boundary conditions have been specified according to

$$\mathbf{u}_\Gamma(\mathbf{x}, t) = \mathbf{0} \quad \text{on } \Gamma_u, \quad \boldsymbol{\sigma}_n(\mathbf{x}, t) = \mathbf{0} \quad \text{on } \Gamma_\sigma,$$

$$\Phi_\Gamma(\mathbf{x}, t) = \hat{\Phi} \sin\left(\frac{2\pi}{\lambda_{IDT}}\right) \sin(\omega t) \quad \text{on } \Gamma_\Phi^{(1)},$$

$$\Phi_\Gamma(\mathbf{x}, t) = 0 \quad \text{on } \Gamma_\Phi^{(2)}, \quad D_n(\mathbf{x}, t) = 0 \quad \text{on } \Gamma_D,$$

where the Dirichlet boundaries are $\Gamma_u := [0, 1.2] \times \{0\}$, $\Gamma_\Phi^{(1)} := [0.2, 0.4] \times \{1.2\}$, $\Gamma_\Phi^{(2)} := [0, 1.2] \times \{0\}$, whereas $\Gamma_\sigma := \partial\Omega \setminus \Gamma_u$ and $\Gamma_D = \partial\Omega \setminus (\Gamma_\Phi^{(1)} \cup \Gamma_\Phi^{(2)})$ stand for the Neumann boundaries.

Concerning the wavelength λ_{IDT} of the interdigital transducer and its operating frequency f , we have made the realistic choice $\lambda_{IDT} = 40\mu\text{m}$ and $f = \frac{\omega}{2\pi} = 100\text{MHz}$.

We have discretized the computational domain by a nested hierarchy of simplicial triangulations of the computational domain Ω generated by uniform refinement of a given coarse mesh. It is well-known that for time-harmonic waves with increasing angular frequency $\omega = \frac{2\pi f}{\lambda}$ the finite element error grows, even if we account for a condition on the meshsize like $h \lesssim \lambda$. A common choice is $h \lesssim \frac{\lambda}{2}$ (i.e. two elements per wavelength), an estimate that guarantees an interpolation property for the used finite element spaces. However, an intrinsic analysis shows that an additional condition like $h \lesssim \sqrt{\lambda^3}$ is needed, if we want to control the finite element error (cf. [28]). Therefore, we have chosen the meshsize for the coarsest grid of the nested hierarchy accordingly.

Figures 11-13 show the amplitudes of the electric potential and the polarized Rayleigh waves, respectively. The amplitudes of the displacement waves are, as expected, in the region of nano-meters. The SAWs are strictly confined to the surface of the substrate. Their penetration depth into the piezoelectric material is in the range of one wavelength.

One of the most outstanding properties of surface acoustic wave propagation on piezoelectric materials is that the velocity of the SAW is independent of the applied frequency. In the case of YXl 128° LiNbO₃ the

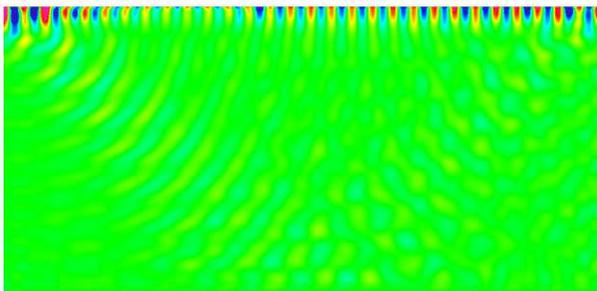


Fig. 11. Electric potential wave

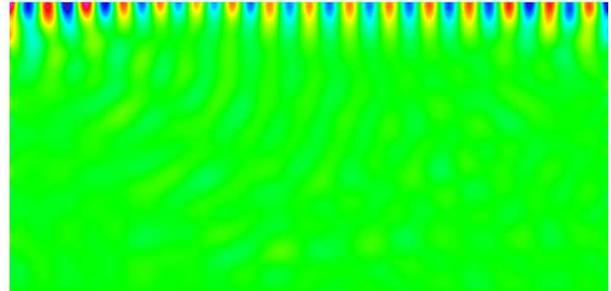


Fig. 14. Electric potential wave for $f = 50$ MHz

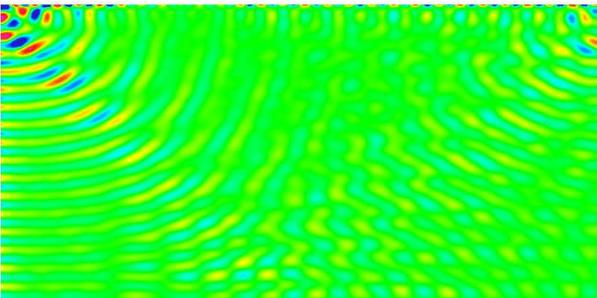


Fig. 12. Displacement wave amplitudes in x_1 -direction

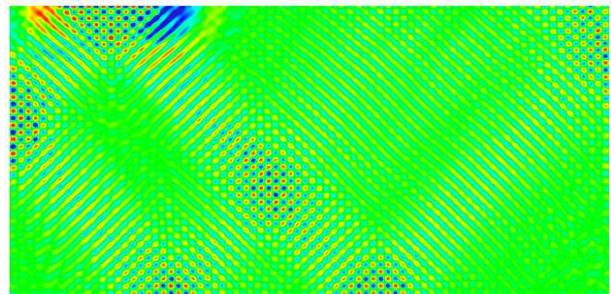


Fig. 15. Bulkwave Excitation

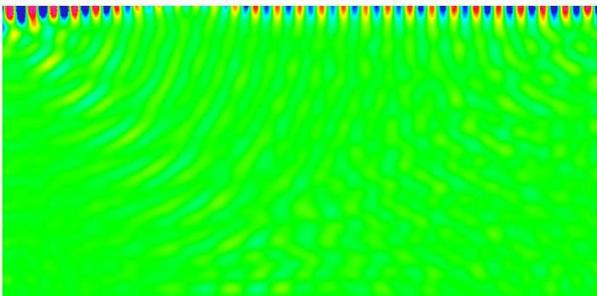


Fig. 13. Displacement wave amplitudes in x_2 -direction

SAW velocity is given by $v = 3992 \frac{m}{s}$, cf. [13]. Thus, for an excitation at the frequency $f = 100$ MHz the theoretical wavelength of the SAW is given as $\lambda = \frac{v}{f} \approx 40 \mu m$. Our calculations show the same wavelength for the SAW. Figure 14 also illustrates the piezoelectric wave for $f = 50$ MHz. The wavelength of the SAW for $f = 100$ MHz is half of that for $f = 50$ MHz.

We remark that the wavelength of an occurring electro-magnetical wave is in the region of approximately 0.3 m. Hence, the negligence of this electro-magnetic wave in the modeling of piezoelectric SAW devices is justified.

The excitation of an IDT on the surface of a piezoelectric material leads to the generation of bulk acoustic waves (BAWs) as well as surface acoustic waves. These

bulk waves can also be observed in our simulations in Figures 11-14. Technologically, they are desirably employed in solid-state circuits [13]. We refer to [16, 19, 23, 24, 52] for finite element approximations of surface acoustic wave propagation in signal processing. However, for the SAW devices under consideration the presence of BAWs is unwanted, since the interference of BAWs with SAWs can lead to a complete loss of functionality of the device. Our approach is sufficiently general to simulate every kind of piezoelectric resonator. In Figure 15 we have used an YXl 38° cut of $LiNbO_3$ to generate a strong bulk acoustic wave at frequency $f = 200$ MHz.

We recall from Chapter 3 that Rayleigh surface waves characteristically show an elliptical displacement, i.e. the displacements in the x_1 - and x_2 -direction are 90° out of phase with one another. Additionally, the amplitude of the surface displacement in the x_2 -direction is larger than that along the SAW propagation axis x_1 . These observations are also true in our numerical computations, see Figures 16 and 17. In Figure 16, the displacements in the x_1 - and x_2 -direction for a certain surface area are depicted. The x_2 -displacements are flipped vertically for easier comparability. In Figure 17 a certain surface area is magnified and the vectors indicate the surface displacements. All numerical calculations show relatively strong reflections from the boundaries of the SAW device. In real devices these reflections are usually avoided by attaching some adhesive material to the side boundaries. An easy way to model such a damping is to introduce an additional term (the so-called *gyroscopic* term)

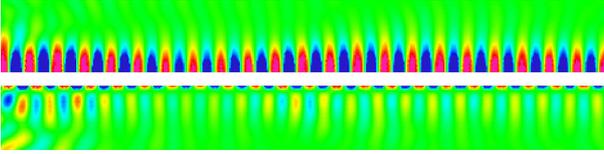


Fig. 16. Phaseshift of x_1 - and x_2 - (flipped) displacements

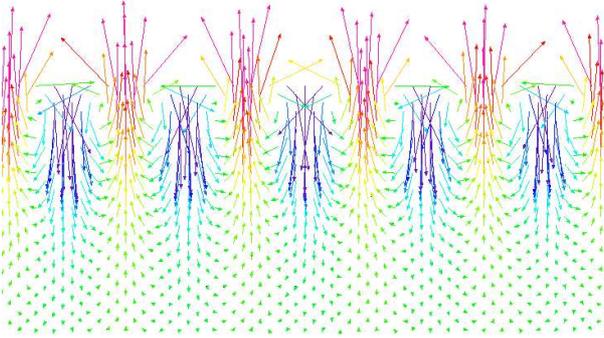


Fig. 17. Displacement vectors for the SAW

into the piezoelectric equations which now become

$$\begin{aligned} \rho \frac{\partial^2 u_i}{\partial t^2} - \frac{\partial \beta_i}{\partial x_j} \frac{\partial^3 u_i}{\partial^2 x_j \partial t} - \\ - c_{ijkl} \frac{\partial^2 u_k}{\partial x_l \partial x_j} - e_{kij} \frac{\partial^2 \Phi}{\partial x_k \partial x_j} = b_i, \\ e_{ikl} \frac{\partial^2 u_k}{\partial x_l \partial x_i} - \epsilon_{ij} \frac{\partial^2 \Phi}{\partial x_j \partial x_i} = \beta_i \end{aligned}$$

cf. e.g. [6, 29]. Introducing such a damping at the boundaries of the bottom and left-hand side we indeed get less reflections and thus less disturbances for the SAW. This gets extraordinarily palpable, if we compare the x_1 -displacements in Figure 12 (calculations without damping) to the new calculations with damping term in Figure 18.

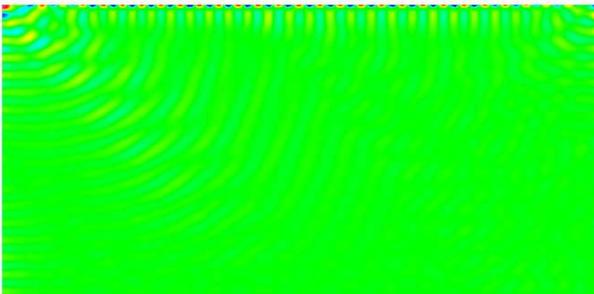


Fig. 18. x_1 -displacements with damping

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